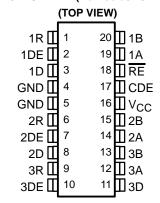
- Three Differential Transceivers in One Package
- Signaling Rates¹ Up to 30 Mbps
- Low Power and High Speed
- Designed for TIA/EIA-485, TIA/EIA-422, ISO 8482, and ANSI X3.277 (HVD SCSI Fast-20) Applications
- Common-Mode Bus Voltage Range
 7 V to 12 V
- ESD Protection on Bus Terminals Exceeds 12 kV
- Driver Output Current up to ±60 mA
- Thermal Shutdown Protection
- Driver Positive and Negative Current Limiting
- Power-Up, Power-Down Glitch-Free Operation
- Pin-Compatible With the SN75ALS171
- Available in Shrink Small-Outline Package

description

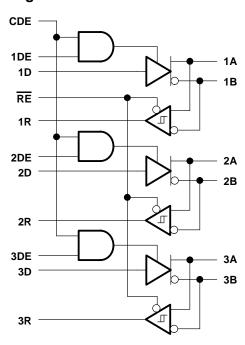
The SN65LBC171 and SN75LBC171 are monolithic integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. Potential applications include serial or parallel data transmission, cabled peripheral buses with twin axial, ribbon, or twisted-pair cabling. These devices are suitable for FAST–20 SCSI and can transmit or receive data pulses as short as 25 ns, with skew less than 3 ns.

These devices combine three 3-state differential line drivers and three differential input line receivers, all of which operate from a single 5-V power supply.

SN65LBC171DB (Marked as BL171) SN75LBC171DB (Marked as LB171) SN65LBC171DW (Marked as 65LBC171) SN75LBC171DW (Marked as 75LBC171)



logic diagram



The driver differential outputs and the receiver differential inputs are connected internally to form three differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus whenever the driver is disabled or $V_{CC} = 0$. These ports feature a wide common-mode voltage range making the device suitable for party-line applications over long cable runs.

The SN75LBC171 is characterized for operation over the temperature range of 0°C to 70°C. The SN65LBC171 is characterized for operation over the temperature range of –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

¹The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).



AVAILABLE OPTIONS[†]

	PACKAGE							
TA	PLASTIC SMALL-OUTLINE (JEDEC MS-013)	PLASTIC SHRINK SMALL-OUTLINE (JEDEC MO-150)						
0°C to 70°C	SN75LBC171DW	SN75LBC171DB						
-40°C to 85°C	SN65LBC171DW	SN65LBC171DB						

TAdd R suffix for taped and reel

Function Tables

EACH DRIVER

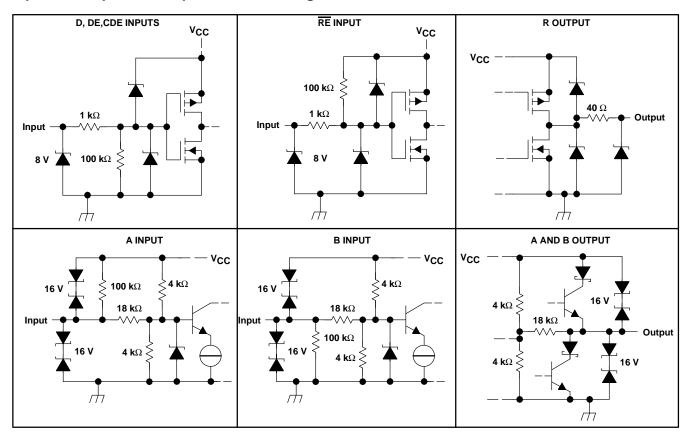
INPUT	EN/	ABLE	OUT	PUTS
D	DE	CDE	Α	В
Н	Н	Н	Н	L
L	Н	Н	L	Н
OPEN	Н	Н	L	Н
Х	L	Χ	Z	Z
Х	Х	L	Z	Z
Х	OPEN	Χ	Z	Z
Х	Х	OPEN	Z	Z

EACH RECEIVER

DIFFERENTIAL INPUT (V _A -V _B)	ENABLE RE	OUTPUT R
V _{ID} ≥ 0.2 V	L	Н
$-0.2 \text{ V} < \text{V}_{1D} < 0.2 \text{ V}$	L	?
$V_{ID} \le -0.2 V$	L	L
X	Н	Z
OPEN	L	Н

H = high level, L = low level, X = irrelevant,Z = high impedance (off), ? = indeterminate

equivalent input and output schematic diagrams



SLLS460A - NOVEMBER 2000 - REVISED FEBRUARY 2001

absolute maximum ratings†

Supply voltage, V _{CC} (see Note 1)	0.3 V to 6 V
Voltage range at any bus I/O terminal (steady state)	–10 V to 15 V
Voltage input range, A and B, (transient pulse through 100 Ω , see Fig	ure 12)30 V to 30 V
Voltage range at any DE, RE, or CDE terminal	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Electrostatic discharge: Human body model (A, B, GND) (see Note 2) 12 kV
All pins	5 kV
Charged-device model (all pins) (see Note 3))
Continuous total power dissipation	See Power Dissipation Rating Table
Storage temperature range, T _{stq}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

- 2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- 3. Tested in accordance with JEDEC Standard 22, Test Method C101.

POWER DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{$A$}} \leq 25^{\circ}\mbox{$C$}$ POWER RATING	DERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	
DB	995 mW	8.0 mW/°C	635 mW	515 mW	
DW	1480 mW	11.8 mW/°C	950 mW	770 mW	

[‡] This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
Voltage at any bus I/O terminal	А, В	-7		12	V
High-level input voltage, VIH	DE, CDE, RE	2		VCC	V
Low-level input voltage, V _{IL}	DE, CDE, RE	0		0.8	V
Differential input voltage, V _{ID}	A with respect to B	-12		12	V
Output ourront	Driver	-60		60	A
Output current	Receiver	-8		8	mA
Operating free cir temperature T.	SN75LBC171	0		70	°C
Operating free-air temperature, T _A	SN65LBC171	-40		85	-0

DRIVER SECTION

electrical characteristics over recommended operating conditions

	PARAMETER	TEST CO	ONDITIONS	MIN	TYP†	MAX	UNIT
VIK	Input clamp voltage D, DE, CDE	I _I = 18 mA		-1.5	-0.7		V
٧o	Open-circuit output voltage (single-ended)	A or B, No load		0		VCC	V
		No load		3.8	4.3	VCC	V
IVOD(SS)I	Steady-state differential output voltage magnitude‡	$R_L = 54 \Omega$,	See Figure 1	1	1.6	2.4	V
	magnitude :	With common-mode	loading, See Figure 2	1	1.6	2.4	V
ΔV _{OD}	Change in differential output voltage magnitude, V _{OD(H)} - V _{OD(L)}			-0.2		0.2	V
Voc(ss)	Steady-state common-mode output voltage	R _L = 54Ω , C _L = 50 pF	See Figure 1	2	2.4	2.8	V
ΔVOC(SS)	Change in steady-state common-mode output voltage (V _{OC(H)} – V _{OC(L)})	- ου pi		-0.2		0.2	V
lį	Input current	D, DE, CDE		-100		100	μΑ
IO	Output current with power off	$V_{CC} = 0 V$,	$V_0 = -7 \text{ V to } 12 \text{ V}$	-700		900	μΑ
los	Short-circuit output current	$V_0 = -7 \text{ V to } 12 \text{ V},$	See Figure 7	-250		250	mA
Icc	Supply current (driver enabled)	D at 0 V or V _{CC} ,	CDE, DE, RE at V _{CC} , No load		14	20	mA

[†] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended operating conditions

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Differential output propagation delay, low-to high		4	8.5	12	
tPHL	Differential output propagation delay, high-to-low	7	4	8.5	11	
t _r	Differential output rise time]	3	7.5	11	
t _f	Differential output fall time	$R_L = 54 \Omega$, $C_L = 50 pF$, See Figure 3	3	7.5	11	ns
t _{sk(p)}	Pulse skew (tpLH - tpHL)	See Figure 3		-	2	
tsk(o)	Output skew§]			1.5	
t _{sk(pp)}	Part-to-part skew¶	7			2	
tPLH	Differential output propagation delay, low-to high		3	7	10	
tPHL	Differential output propagation delay, high-to-low		3	7.5	10	
t _r	Differential output rise time],	3	7.5	12	
t _f	Differential output fall time	See Figure 4, (HVD SCSI double-terminated load)	3	7.5	12	ns
t _{sk(p)}	Pulse skew (tpLH - tpHL)	(11VB GGGI double-terminated idad)			3	
t _{sk(o)}	Output skew§				1.5	
t _{sk(pp)}	Part-to-part skew¶				2.5	
^t PZH	Output enable time to high level	Con Figure 5		15	25	
^t PHZ	Output disable time from high level	See Figure 5		18	25	ns
^t PZL	Output enable time to low level	Soo Figure 6		10	25	no
^t PLZ	Output disable time from low level	See Figure 6		17	25	ns

[§] Output skew (t_{Sk(O)}) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together. ¶ Part-to-part skew (t_{Sk(pp)}) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.



[‡] The minimum V_{OD} may not fully comply with TIA/EIA-485-A at operating temperatures below 0°C. System designers should take the possibly lower output signal into account in determining the maximum signal-transmission distance.

RECEIVER SECTION

electrical characteristics over recommended operating conditions

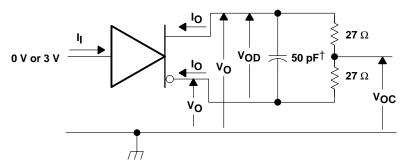
	PARAMETER	TEST CON	IDITIONS	MIN	TYP	MAX	UNIT
V _{IT+}	Positive-going differential input voltage threshold					0.2	V
V _{IT} –	Negative-going differential input voltage threshold			-0.2			V
V _{hys}	Hysteresis voltage (V _{IT+} – V _{IT-})				40		mV
Vон	High-level output voltage	V_{ID} = 200 mV, I_{OH} = -	-8 mA, see Figure 10	4	4.7	VCC	V
VOL	Low-level output voltage	$V_{ID} = -200 \text{ mV}, I_{OL} = -200 \text{ mV}$	–8 mA, see Figure 10	0	0.2	0.4	V
Ī.	Line input current	Other input = 0 V	V _I = 12 V			0.9	mA
11	Line input current	Other input = 0 v	V _I = −7 V	-0.7			IIIA
II	Input current	RE		-100		100	μΑ
R _I	Input resistance	A, B		12			kΩ
Icc	Supply current (receiver enabled)	A, B, D open, RE, D	E, and CDE at 0 V			16	mA

 $[\]uparrow$ All typical values are at V_{CC} = 5 V and T_A = 25°C.

switching characteristics over recommended operating conditions

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low-to-high level output		7		16	ns
t _{PHL}	Propagation delay time, high-to-low level output	Vin - 3 V to 3 V Son Figure 0	7		16	ns
t _r	Receiver output rise time	$V_{ID} = -3 \text{ V to } 3 \text{ V, See Figure } 9$		1.3	3	ns
t _f	Receiver output fall time			1.3	3	ns
^t PZH	Receiver output enable time to high level	See Figure 10		26	40	
^t PHZ	Receiver output disable time from high level	See Figure 10			40	ns
tPZL	Receiver output enable time to low level	See Figure 44		29	40	
^t PLZ	Receiver output enable time to high level	See Figure 11			40	ns
t _{sk(p)}	Pulse skew ((tpLH - tpHL)				2	ns
t _{sk(o)}	Output skew [‡]				1.5	ns
t _{sk(pp)}	Part-to-part skew§				3	ns

[‡] Output skew (t_{sk(o)}) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together. § Part-to-part skew (t_{sk(pp)}) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.



†Includes probe and jig capacitance

Figure 1. Driver Test Circuit, $V_{\mbox{\scriptsize OD}}$ and $V_{\mbox{\scriptsize OC}}$ Without Common-Mode Loading

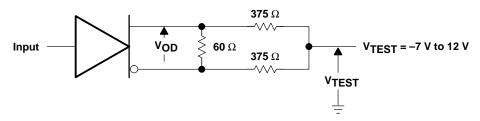
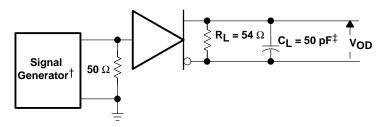


Figure 2. Driver Test Circuit, $V_{\mbox{\scriptsize OD}}$ With Common-Mode Loading



† PRR = 1 MHz, 50% Duty Cycle, $t_{\rm f}$ < 6 ns, $t_{\rm f}$ < 6 ns, $Z_{\rm O}$ = 50 Ω ‡ Includes Probe and Jig Capacitance

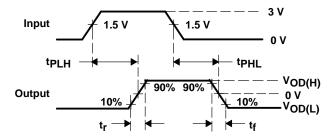
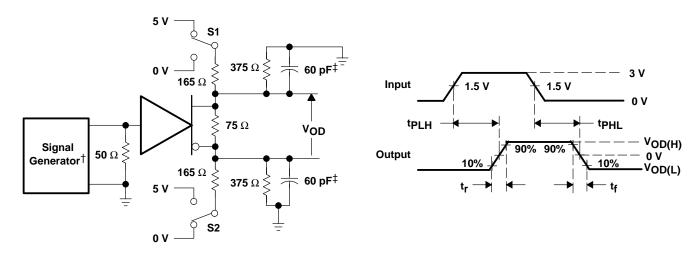
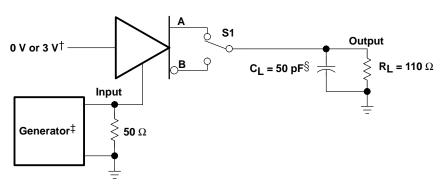


Figure 3. Driver Switching Test Circuit and Waveforms, 485-Loading



- † PRR = 1 MHz, 50% Duty Cycle, t_{f} < 6 ns, t_{f} < 6 ns, Z_{O} = 50 Ω
- ‡ Includes Probe and Jig Capacitance

Figure 4. Driver Switching Test Circuit and Waveforms, HVD SCSI-Loading (double terminated)



- † 3 V if testing A output, 0 V if testing B output
- ‡ PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_0 = 50 Ω
- § Includes Probe and Jig Capacitance

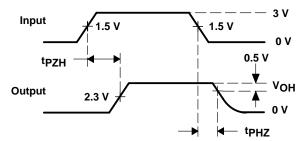
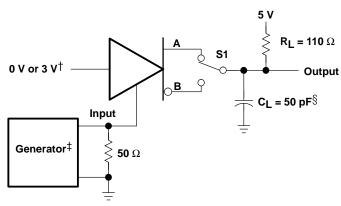
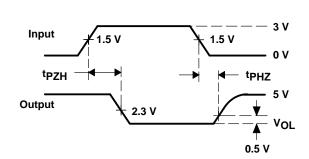


Figure 5. Driver Enable/Disable Test, High Output





- † 0 V if testing A output, 3 V if testing B output
- ‡ PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_O = 50 Ω
- § Includes Probe and Jig Capacitance

Figure 6. Driver Enable/Disable Test, Low Output

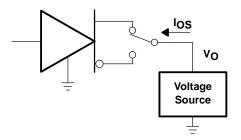


Figure 7. Driver Short-Circuit Test

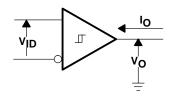
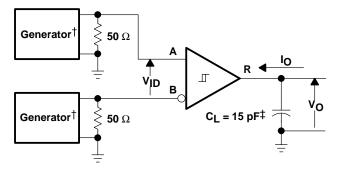


Figure 8. Receiver DC Parameters



- † PRR = 1 MHz, 50% Duty Cycle, $t_{\rm f}$ < 6 ns, $t_{\rm f}$ < 6 ns, $Z_{\rm O}$ = 50 Ω
- ‡ Includes Probe and Jig Capacitance

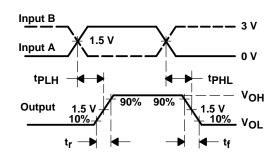
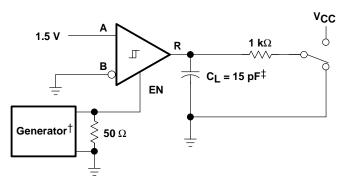
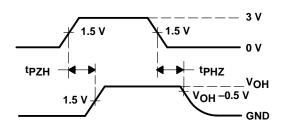


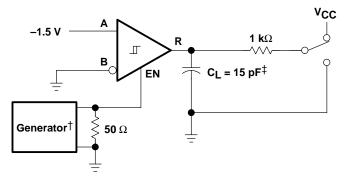
Figure 9. Receiver Switching Test Circuit and Waveforms

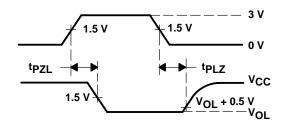




- † PRR = 1 MHz, 50% Duty Cycle, t_{f} < 6 ns, t_{f} < 6 ns, Z_{O} = 50 Ω
- ‡ Includes Probe and Jig Capacitance

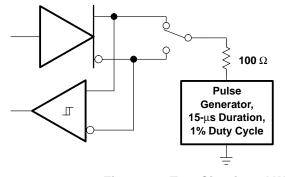
Figure 10. Receiver Enable/Disable Test, High Output





- † PRR = 1 MHz, 50% Duty Cycle, $t_{\rm f}$ < 6 ns, $t_{\rm f}$ < 6 ns, $Z_{\rm O}$ = 50 Ω
- ‡ Includes Probe and Jig Capacitance

Figure 11. Receiver Enable/Disable Test, Low Output



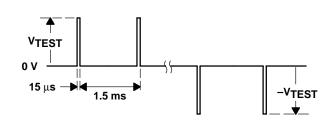
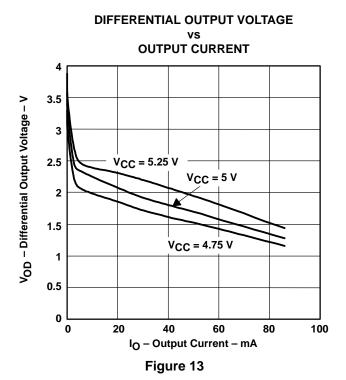
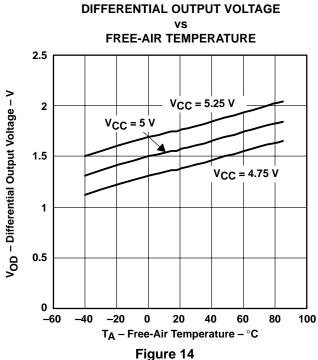
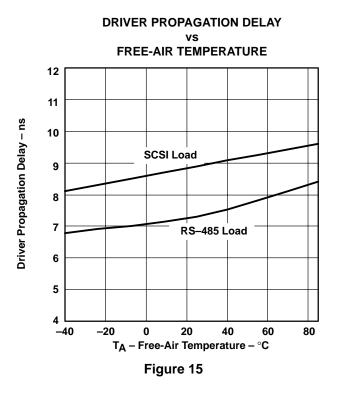
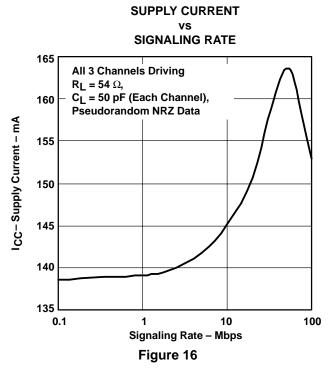


Figure 12. Test Circuit and Waveform, Transient Over Voltage Test









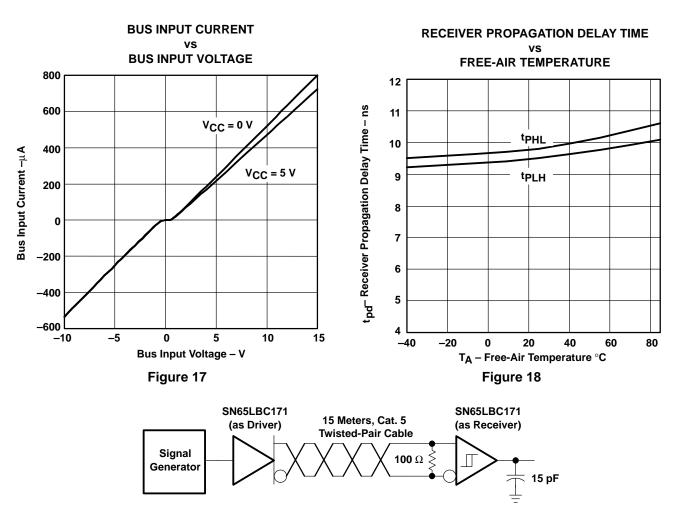


Figure 19. Circuit Diagram for Signaling Characteristics

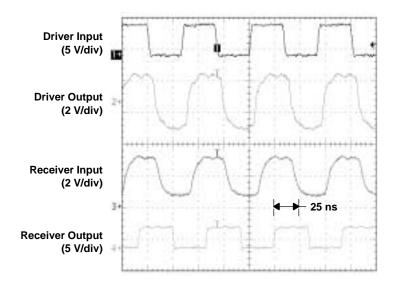


Figure 20. Signal Waveforms at 30 Mbps

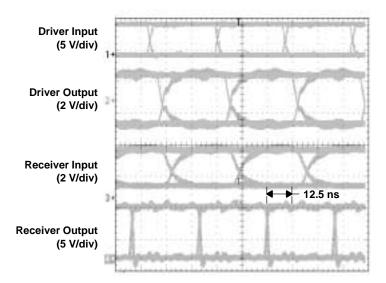


Figure 21. Eye Patterns, Pseudorandom Data at 30 Mbps

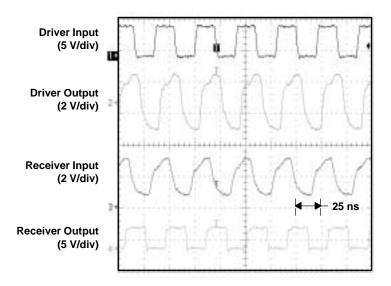


Figure 22. Signal Waveforms at 50 Mbps

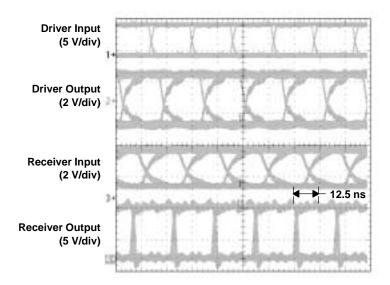


Figure 23. Eye Patterns, Pseudorandom Data at 50 Mbps

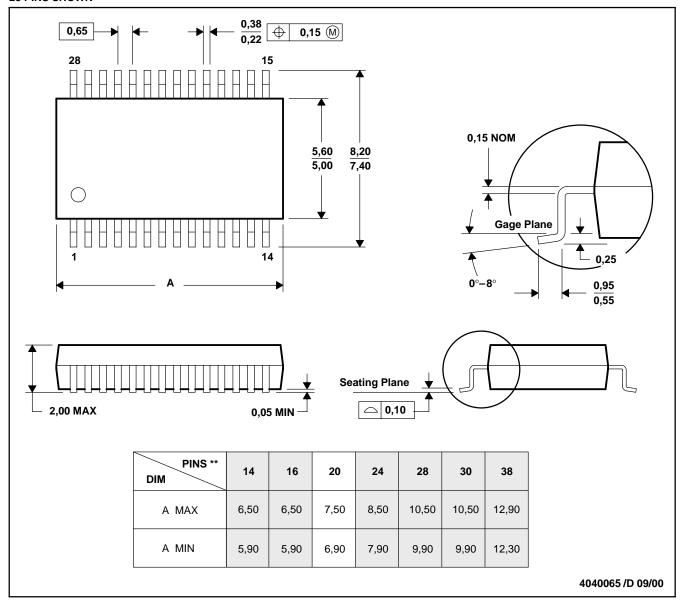
SLLS460A - NOVEMBER 2000 - REVISED FEBRUARY 2001

MECHANICAL DATA

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

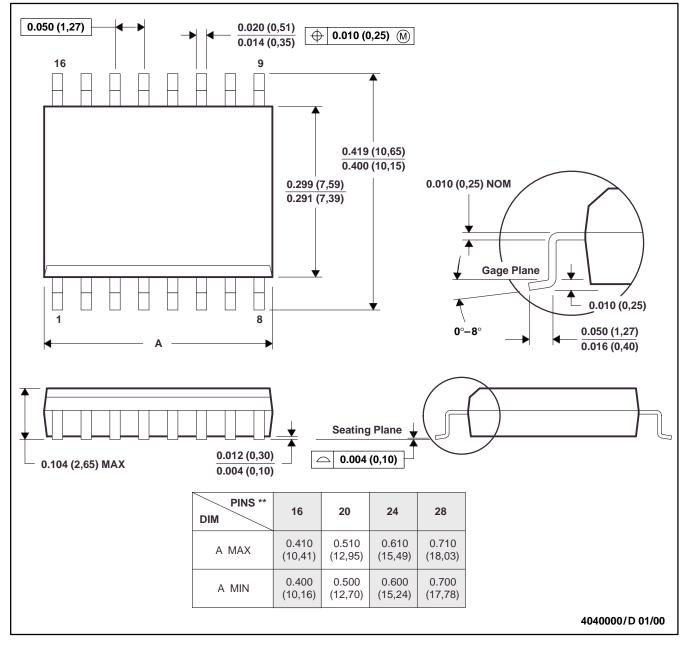
D. Falls within JEDEC MO-150

MECHANICAL DATA

DW (R-PDSO-G**)

16 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013



www.ti.com 17-Jun-2023

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN65LBC171DB	ACTIVE	SSOP	DB	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL171	Samples
SN65LBC171DW	LIFEBUY	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC171	
SN65LBC171DWR	LIFEBUY	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC171	
SN75LBC171DB	LIFEBUY	SSOP	DB	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LB171	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

www.ti.com 17-Jun-2023

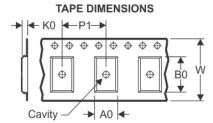
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC171DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

www.ti.com 5-Jan-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC171DWR	SOIC	DW	20	2000	367.0	367.0	45.0

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65LBC171DB	DB	SSOP	20	70	530	10.5	4000	4.1
SN65LBC171DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN75LBC171DB	DB	SSOP	20	70	530	10.5	4000	4.1

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated